# TSC **S**b

# TS13002

# High Voltage NPN Transistor

TO-92



Pin assignment:

- 1. Emitter
- 2. Collector
- 3. Base

 $BV_{CEO} = 400V$ 

 $BV_{CBO} = 700V$ 

Ic = 0.2A

 $V_{CE (SAT)}$ , = 0.5V @ Ic / Ib = 100mA / 10mA

### **Features**

- High voltage.
- ♦ High speed switching

#### **Structure**

- Silicon triple diffused type.
- ♦ NPN silicon transistor

## **Ordering Information**

Part No.	Packing	Package	
TS13002CT B0	Bulk	TO-92	
TS13002CT A3	AMMO pack	TO-92	

## **Absolute Maximum Rating** (Ta = 25 °C unless otherwise noted)

Parameter		Symbol	Limit	Unit
Collector-Base Voltage		$V_{CBO}$	700V	V
Collector-Emitter Voltage		V <sub>CEO</sub>	400V	V
Emitter-Base Voltage		V <sub>EBO</sub>	9	V
Collector Current	DC	Ic	0.2	Α
	Pulse		0.5	
Collector Power Dissipation		P <sub>D</sub>	0.6	W
Operating Junction Temperature		T <sub>J</sub>	+150	°C
Operating Junction and Storage Temperature Range		T <sub>STG</sub>	- 55 to +150	°C

Note: 1. Single pulse, Pw = 5mS, Duty <= 10%

## Electrical Characteristics (Ta = 25 °C unless otherwise noted)

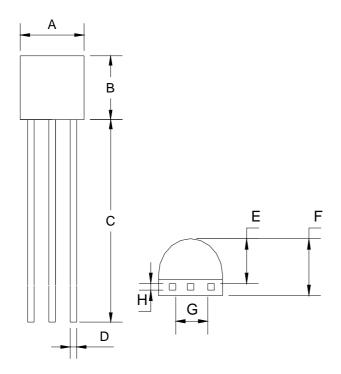
Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Static						
Collector-Base Voltage	$I_C = 10 \text{mA}, I_B = 0$	BV <sub>CBO</sub>	700			V
Collector-Emitter Breakdown Voltage	$I_{C} = 1 \text{mA}, I_{E} = 0$	BV <sub>CEO</sub>	400			V
Emitter-Base Breakdown Voltage	$I_E = 1 \text{mA}, I_C = 0$	BV <sub>EBO</sub>	9			V
Collector Cutoff Current	$V_{CB} = 700V, I_{E} = 0$	I <sub>CBO</sub>	-		100	uA
Emitter Cutoff Current	$V_{EB} = 7V, I_{C} = 0$	I <sub>EBO</sub>			10	uA
Collector-Emitter Saturation Voltage	I <sub>C</sub> / I <sub>B</sub> = 200mA / 20mA	V <sub>CE(SAT)1</sub>			2.5	V
	$I_C / I_B = 100 \text{mA} / 10 \text{mA}$	V <sub>CE(SAT)2</sub>			0.5	
DC Current Gain	$V_{CE} = 10V, I_{C} = 10uA$	h <sub>FE</sub>	10		40	
DC Current Gain	$V_{CE} = 10V, I_{C} = 100mA$	h <sub>FE</sub>	20		40	
DC Current Gain	$V_{CE} = 10V, I_{C} = 200mA$	h <sub>FE</sub>	10		40	
Frequency	$V_{CE} = 10V, I_{C} = 0.1A$	f <sub>T</sub>	4			MHz
Output Capacitance	$V_{CB} = 10V, f = 0.1MHz$	Cob	I	21		pF
Turn On Time	$V_{CC} = 125V, I_C = 100mA,$	t <sub>ON</sub>	-	1.1		uS
Storage Time	$I_{B1} = I_{B2} = 20\text{mA},$	t <sub>STG</sub>	-		4	uS
Fall Time	R <sub>L</sub> = 125ohm	t <sub>f</sub>			0.7	uS

Note: pulse test: pulse width <=5mS, duty cycle <=10%

TS13002 1-1 2004/06 rev. A



# TO-92 Mechanical Drawing



TO-92 DIMENSION					
DIM	MILLIMETERS		INCHES		
	MIN	MAX	MIN	MAX	
Α	4.30	4.70	0.169	0.185	
В	4.30	4.70	0.169	0.185	
С	14.30(typ)		0.563(typ)		
D	0.43	0.49	0.017	0.019	
Ε	2.19	2.81	0.086	0.111	
F	3.30	3.70	0.130	0.146	
G	2.42	2.66	0.095	0.105	
Н	0.37	0.43	0.015	0.017	